



AMP4015P SOLID STATE PULSE HIGH POWER AMPLIFIER

FEATURES

High power GaN pulse devices
 Suitable for X-Band linear pulse applications
 Built-in Ethernet Control and Protection circuits
 High reliability and ruggedness

ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	9.3 - 9.5 GHz	
Peak Output Power	8000 Watt Min	5% Duty Cycle
Input Power	0 dBm Nom	Pulsed
Saturated Gain	69 dB Min	
Pulse Width	0.5 - 30 μ Sec	Measured @ 50% pt.
Duty Cycle	5 % Max	
Pulse Repetition Frequency (PRF)	25 KHz Max	
Rise / Fall Time	50 nSec	
Input / Output VSWR	1.5 : 1	Relative to 50 Ohm
Harmonics	-20 dBc Max	Internal Harmonics Filter
Out of Band Spurious levels	-50 dBc Max	
Load VSWR	2.5 : 1	Without damage
Gate Control Inputs	Differential TTL or RS-422	TTL gating pulse must precede RF by 2 μ Sec
AC Input Voltage	115 VAC, 3 Phase, 400 Hz	
RF Output Sample	-60 dB	Continuous DC Voltage

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50°C	
Vibrations	MIL-STD 810G, Method 514.6	
Altitude	10,000 feet	30,000 feet non-operating

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions W x H x D	17" x 12.75" x 24" Max	7U, 19" rack
Weight	90 pound Max	
RF Input Connector	SMA (F) Jack	
RF Output Connector	WR-112 Waveguide flange	Waveguide pressure sensor
RF Sample Port	SMA (F) Jack	
AC Power	MS3122E14-5P	or similar
Transmit Gating Connector	MS circular or similar	
Monitor & Control	Ethernet RJ-45 circular connector TCP/IP RS422/485 D-sub 9S port for redundancy	
Cooling	Built in Fan Cooling	Front Inlet, Rear outlet
Elapse Hour Meter	Internally tracked via software	Ethernet status message

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OUTLINE DRAWING

